



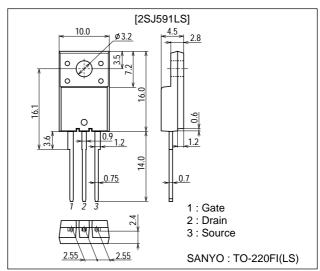
DC / DC Converter Applications

Features

- · Low ON-resistance.
- 4V drive.

Package Dimensions

unit : mm 2078C



Specifications

Absolute Maximum Ratings at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|-----------------------------|------------------|------------------------|-------------|------|
| Drain-to-Source Voltage | V _{DSS} | | -60 | V |
| Gate-to-Source Voltage | VGSS | | ±20 | V |
| Drain Current (DC) | ID | | -28 | Α |
| Drain Current (Pulse) | IDP | PW≤10μs, duty cycle≤1% | -112 | Α |
| Allowable Power Dissipation | Do | | 2.0 | W |
| | PD | Tc=25°C | 35 | W |
| Channel Temperature | Tch | | 150 | °C |
| Storage Temperature | Tstg | | -55 to +150 | °C |

Electrical Characteristics at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | | | 1.1-24 |
|--|-----------------------|---|---------|-----|------|--------|
| | | | min | typ | max | Unit |
| Drain-to-Source Breakdown Voltage | V(BR)DSS | ID=-1mA, VGS=0 | -60 | | | V |
| Zero-Gate Voltage Drain Current | IDSS | VDS=-60V, VGS=0 | | | -10 | μΑ |
| Gate-to-Source Leakage Current | IGSS | V _{GS} =±16V, V _{DS} =0 | | | ±10 | μΑ |
| Cutoff Voltage | VGS(off) | V _{DS} =-10V, I _D =-1mA | -1.0 | | -2.4 | V |
| Forward Transfer Admittance | yfs | V _{DS} =-10V, I _D =-14A | 18 | 26 | | S |
| Static Drain-to-Source On-State Resistance | R _{DS} (on)1 | I _D =-14A, V _{GS} =-10V | | 27 | 35 | mΩ |
| | RDS(on)2 | I _D =-14A, V _G S=-4V | | 38 | 53 | mΩ |

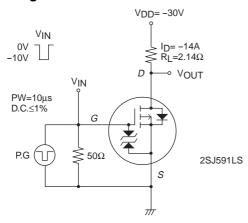
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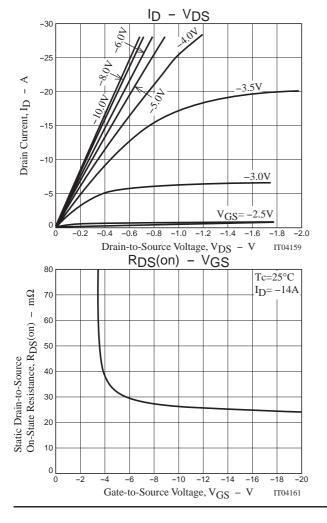
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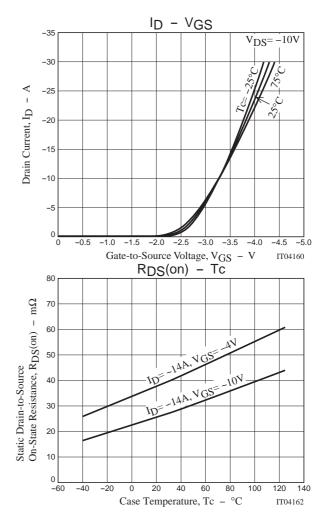
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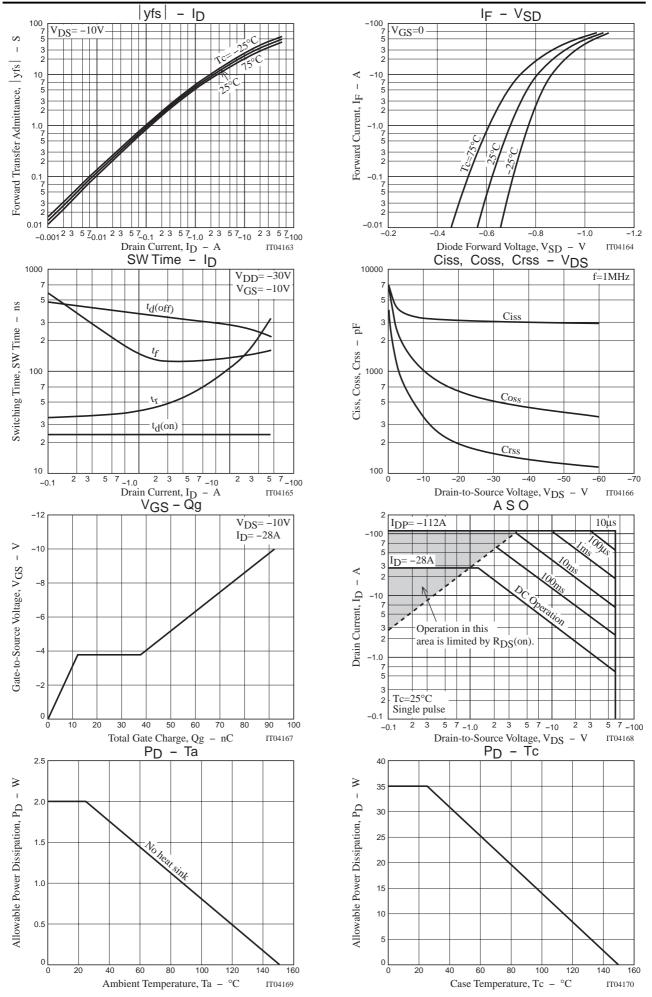
| Parameter | Cumpleal | Conditions | | Ratings | | |
|-------------------------------|----------------------|--|-----|---------|------|------|
| | Symbol | | min | typ | max | Unit |
| Input Capacitance | Ciss | V _{DS} =-20V, f=1MHz | | 3100 | | pF |
| Output Capacitance | Coss | V _{DS} =-20V, f=1MHz | | 640 | | pF |
| Reverse Transfer Capacitance | Crss | VDS=-20V, f=1MHz | | 200 | | pF |
| Turn-ON Delay Time | t _d (on) | See specified Test Circuit. | | 24 | | ns |
| Rise Time | t _r | See specified Test Circuit. | | 140 | | ns |
| Turn-OFF Delay Time | t _d (off) | See specified Test Circuit. | | 270 | | ns |
| Fall Time | tf | See specified Test Circuit. | | 140 | | ns |
| Total Gate Charge | Qg | V _{DS} =-10V, V _{GS} =-10V, I _D =-28A | | 92 | | nC |
| Gate-to-Source Charge | Qgs | V _{DS} =-10V, V _{GS} =-10V, I _D =-28A | | 12 | | nC |
| Gate-to-Drain "Miller" Charge | Qgd | V _{DS} =-10V, V _{GS} =-10V, I _D =-28A | | 26 | | nC |
| Diode Forward Voltage | V _{SD} | I _S =-28A, V _G S=0 | | -0.92 | -1.2 | V |

Switching Time Test Circuit









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